

SANYO Semiconductors **DATA SHEET**

LA7860 LA7860M

Monolithic Linear IC For Multisynch Display Deflection IC

Overview

The LA7860, 7860M display deflection integrated circuit supports multisynch and high-definition displays. Implemented through proprietary Sanyo circuit technology, it offers unsurpassed low-noise performance.

Its outstanding characteristic is the simplified processing it offers for screen settling in response to fluctuations in horizontal scan frequency, which has required numerous components and complex control procedures in the past. This has been made possible through a combination of the conventional phase shift function (H. SHIFT) with a new horizontal oscillation frequency dependent phase shift function (S. GAIN) implemented internally in the IC.

Control pins for various other internal functions support control at 0 to 2.5V dc, making it possible to simply control horizontal oscillation frequency and horizontal and vertical image phase directly with a microcomputer. When used in conjunction with an interface such as a DAC, it will also support system bus applications.

Features

• Supports multisynch displays

DC control

• Low noise

• Supports polar input signals

• TTL output

Functions

- Horizontal frequency independent screen phase shift (H. SHIFT)
- Horizontal frequency dependent screen phase shift (S. GAIN)
- Vertical screen phase shift (V. SHIFT)
- Horizontal oscillation frequency control (H. OSC)
- Horizontal synchronization and detection (H. LOCK)
- Vertical blanking output (V. BLK)
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Specifications

Maximum Ratings at Ta = 25°C

Parameter	Symbol	Conditions	Ratings	Unit
Maximum supply voltage	V ₂₁ max		14	٧
Maximum supply current	I ₁₄ max		75	mA
Maximum rush current	I ₁₆ si max		10	mA
	I ₂₄ si max		10	mA
	I ₂₅ si max		2	mA
FBP minimum input voltage	V _{IN18} min		-5	٧
Allowable power dissipation	Pd max	[LA7860] * ¹	0.95	W
		Ta ≤ 70°C [LA7860M] *2	1.1	W
Operating temperature	Topr		-10 to +70	°C
Storage temperature	Tstg		-55 to +150	°C

Note: 1. TC \leq 100°C, Pd max = 0.95W (The case temperature is the temperature of pin 23.) 2. Measured when mounted on a 100 \times 70 \times 1.15 mm³, glass epoxy printed circuit board.

Recommended Operating Conditions at Ta = 25°C

Parameter	Symbol	Conditions	Ratings	Unit
Recommended supply voltage	V ₂₁		12	V
Recommended supply current	I ₁₄		60	mA
Operating supply voltage	V ₂₁ op		10.5 to 13.5	V
Operating supply current	I ₁₄ op		55 to 65	mA
Recommended input voltage	V ₁		2	Vp-p
Operating input voltage	V ₃₀		2	Vp-p
	V ₁ op		1.0 to 3.0	Vp-p
	V ₃₀ op		1.0 to 3.0	Vp-p
Maximum horizontal input width	V _{IN1} max		3/20	Th
Maximum vertical input width	V _{IN30} max		3	ms
Maximum FBP input width	V _{IN18} max		1/5+Tdelf	Th

Where Th is one horizontal cycle, and Tdelf is 20-pin operation period.

LA7860, 7860M

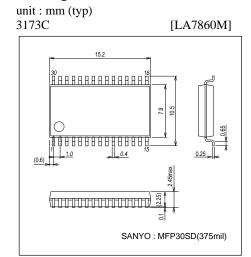
Electrical Characteristics at $Ta=25^{\circ}C,\,V_{CC21}=12V,\,I_{CC14}=60 \mathrm{mA}$

Parameter	Symbol	Conditions		Ratings		
			Min	Тур	max	Unit
V _{CC} 21 current dissipation	l ₂₁		4.2	5.6	7.0	mA
V _{CC} 14 supply voltage	V ₁₄		8.5	9.0	9.5	٧
Maximum vertical pull-in frequency	Fv max		180	210	240	Hz
Minimum vertical pull-in frequency	Fv min		30.0	37.5	45.0	Hz
Maximum vertical blanking width	Wb max		740	875	1010	μS
Minimum vertical blanking width	Wb min		340	400	460	μS
Blanking pulse output high voltage	Vbh		4.5	5	5.5	V
Blanking pulse output low voltage	Vbl				0.3	V
Vertical blanking output current	I ₂₅ so		1.6	2		mA
Vertical output pulse width	Wvd		255	300	345	μs
Vertical output maximum shift	Pv max		400	475	550	μs
Vertical output delay	Dv min				1	μs
Vertical output voltage high	Vdvh		4.5	5.0	5.5	V
Vertical output voltage low	VdvI				0.3	V
Vertical output current	I ₂₄ so		1.7	2.2		mA
Vertical oscillation start voltage	Fvst			5.0	6.0	V
Horizontal oscillation start voltage	F _H st			5.0	6.0	V
Minimum horizontal oscillation frequency	F _H min		25.7	27.1	28.5	kHz
Minimum horizontal oscillation frequency	F _H max		89.5	94.6	99.7	kHz
Horizontal frequency pull-in range	Hpull		3.5	4.1		%
AFC control current	lafc		500	630	760	μΑ
Horizontal output high voltage	Vhdh		4.5	5.0	5.5	V
Horizontal output low voltage	Vhdl				0.3	V
Minimum horizontal phase	Ph min	Tfbp = 2.6 μs	-2.0	-1.4	-0.8	μs
Maximum horizontal phase	Ph max	Tfbp = 2.6 μs	3.5	4.5	5.5	μs
Frequency dependent maximum phase	Pf max	Tfbp = 2.6 μs	23	26.5	30	%
Frequency dependent minimum phase	Pf min	Tfbp = 2.6 μs	-3	0	3	%
Minimum horizontal output pulse width	Wh min		21	24	27	%
Maximum horizontal output pulse width	Wh max		64	67	70	%
Horizontal output current	I ₁₆ so		1.7	2.3		mA
Synchronized output voltage	Vco		4.5	5	5.5	V
Asynchronized output voltage	Vnco				0.3	V
FBP input voltage	Vfbp		1.2	1.5	1.8	V
EN input voltage	Ven		2.0	2.5	3.0	V

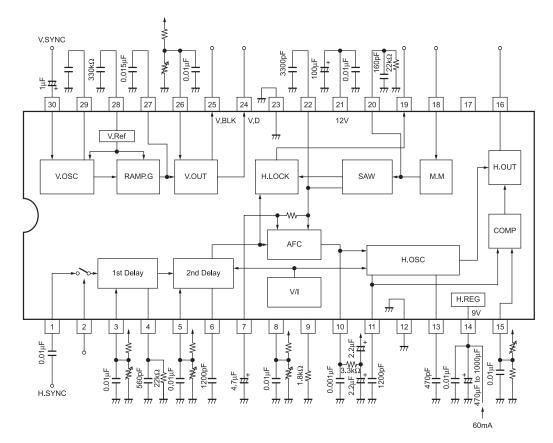
Package Dimensions

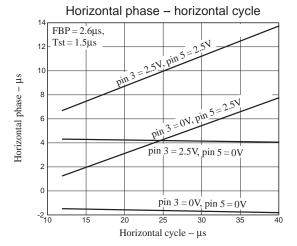
unit: mm (typ) 3061 [LA7860] SANYO: DIP-30S (400mil)

Package Dimensions



Block Diagram and Peripheral Circuit





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